

Schottky Barrier Rectifier

INCHANGE SEMICONDUCTOR

MBR1090CT

FEATURES

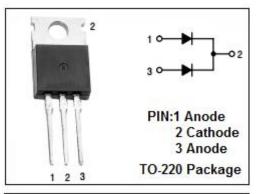
- Schottky Barrier Chip
- Low Power Loss/High Efficiency
- High current capability, low forward voltage drop
- High surge capability
- · Guardring for overvoltage protection
- High temperature soldering guaranteed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

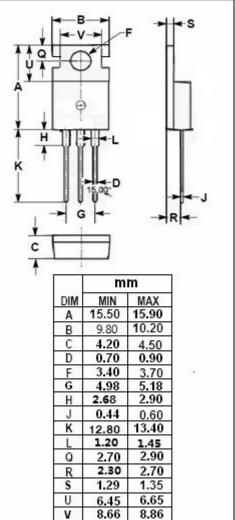
APPLICATIONS

• Designed for low-voltage, high frequency inverters, free wheeling and polarrity protection applications .

| ADSOLUTE MAXIMUM RATINGS(Ta=25 C) | | | | | | |
|--|--|---------|----------------------|--|--|--|
| SYMBOL | PARAMETER VALUE | | UNIT | | | |
| V _{RRM} V _{RWM} VR | Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | 90 | V | | | |
| V _{R(RMS}) | RMS Reverse Voltage | 63 | V | | | |
| IF(AV) | Average Rectified Forward Current (Rated V_R) T _C = 100 $^\circ$ C | 10 | А | | | |
| IFSM | Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half- wave, single phase, 60Hz) | 120 | A | | | |
| TJ | Junction Temperature | 150 | °C | | | |
| T _{stg} | Storage Temperature Range | -65~150 | °C | | | |
| dv/dt | v/dt Voltage Rate of Change (Rated V _R) | | V/ µ s | | | |

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)





isc website: <u>www.iscsemi.com</u>



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THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------|--------------------------------------|-----|--------------|
| Rth j-c | Thermal Resistance, Junction to Case | | °C /W |

ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 μ s,Duty Cycle \leq 1%)

| SYMBOL | PARAMETER | CONDITIONS | MAX | UNIT |
|----------------|---------------------------------------|--|------------------------------|------|
| VF | Maximum Instantaneous Forward Voltage | I _F = 5A ; T _C = 25 [°] C I _F = 5A ; T _C = 125 [°] C I _F = 10A ; T _C = 25 [°] C I _F = 10A ;T _C =125 [°] C | 0.85 0.75 0.95 0.85 | V |
| I _R | Maximum Instantaneous Reverse Current | Rated DC Voltage, T _C = 25 $^{\circ}$ C Rated DC Voltage, T _C = 125 $^{\circ}$ C | 0.1 50 | mA |

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